## (19) World Intellectual Property Organization International Bureau



#### 

### (43) International Publication Date 5 June 2003 (05.06.2003)

#### **PCT**

# (10) International Publication Number WO 03/046536 A1

(51) International Patent Classification<sup>7</sup>: G01N 27/12

(21) International Application Number: PCT/EP02/13309

(22) International Filing Date:

26 November 2002 (26.11.2002)

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data: 01 128 064.1 26 November 2001 (26.11.2001) EP

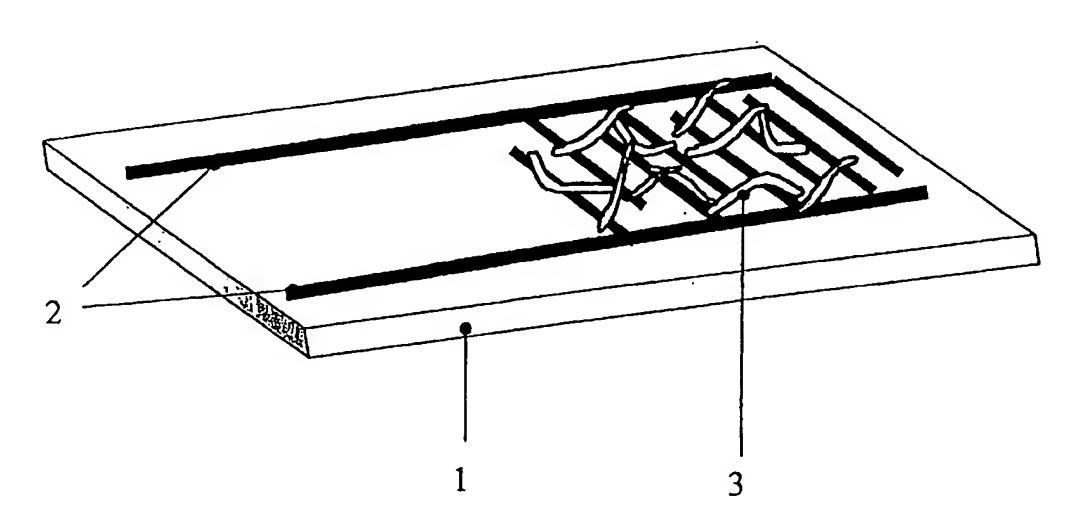
- (71) Applicants (for all designated States except US): SONY INTERNATIONAL (EUROPE) GMBH [DE/DE]; Kemperplatz 1, 10785 Berlin (DE). MAX-PLANCK-GESELLSCHAFT ZUR FÖRDERUNG DER WISSENSCHAFTEN E.V. [DE/DE]; Hofgartenstrasse 8, 80539 München (DE).
- (72) Inventors; and
- (75) Inventors/Applicants (for US only): BESNARD, Isabelle

[FR/DE]; Advanced Technologie Center Stuttgart, Sony International (Europe) GmbH, Heinrich-Hertz-Strasse 1, 70327 Stuttgart (DE). VOSSMEYER, Tobias [DE/DE]; Advanced Technologie Center Stuttgart, Sony International (Europe) GmbH, Heinrich-Hertz-Strasse 1, 70327 Stuttgart (DE). YASUDA, Akio [JP/DE]; c/o Advanced Technologie Center Stuttgart, Sony International (Europe) GmbH, Heinrich-Hertz-Strasse 1, 70327 Stuttgart (DE). BURGHARD, Marko [DE/DE]; Max-Planck-Institute for Solid State Research, Heisenbergstrasse 1, 70569 Stuttgart (DE). SCHLECHT, Ulrich [DE/DE]; Max-Planck-Institute for Solid State Research, Heinsenbergstrasse 1, 70569 Stuttgart (DE).

- (74) Agent: HOFFMANN, Jörg, Peter; Müller, Hoffmann & Partner, Patentanwälte, Innere Wiener Strasse 17, 81667 München (DE).
- (81) Designated States (national): AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, OM, PH, PL, PT, RO, RU, SD, SE, SG,

[Continued on next page]

(54) Title: THE USE OF 1D SEMICONDUCTOR MATERIALS AS CHEMICAL SENSING MATERIALS, PRODUCED AND OPERATED CLOSE TO ROOM TEMPERATURE



WO 03/046536

(57) Abstract: The application relates to a chemical sensor device comprising a substrate (1), a sensor medium (3) formed on the substrate, the sensor medium comprising one-dimensional nanoparticles, wherein the one-dimensional nanoparticles essentially consist of a semiconducting  $A_xB_y$  compound, e.g.  $V_2O_5$  and detection means (2) for detecting a change of a physical property of the sensor medium e.g. conductivity. The porosity of the sensor medium supports a fast access of the analyte to the sensing material and therefore a fast response of the sensor. The selectivity and sensitivity of the sensor can be tailored by doping the one-dimensional nanoscale material with different dopants or by varying the dopant concentration. Sensitivity of the sensor device to an analyte, preferably an amine, can be increased by increasing relative humidity of the sample to at least 5 %.